

APPENDIX

5. (Amended) The high frequency receiver (1) according to ~~one of the claims 2-4~~, characterised in that the quadrature low noise amplifier (2-1, 2-2) comprises a cascode arrangement of semiconductors (15).

7. (Amended) The high frequency receiver (1) according to claim 5 ~~or 6~~, characterised in that ~~across the cascode arrangement of semiconductors (15) there is~~ connected a capacitor (C). *a capacitor is connected*

8. (Amended) The high frequency receiver (1) according to ~~one of the claims 2-7~~, characterised in that the high frequency receiver (1) comprises two quadrature choppers (10-1, 10-2) coupled between respective outputs (4, 5) of the quadrature low noise amplifiers (2-1, 2-2) and respective inputs of the quadrature mixers (3-1, 3-2).

10. (Amended) A communication device, for example a radio receiver, transceiver or a telephone, such as a mobile or cordless telephone provided with a high frequency receiver (1) according to ~~one of the claims 2-9~~. *minor*

11. (Amended) A quadrature low noise amplifier (2-1, 2-2) for application in the high frequency receiver (1) according to ~~one of the claims 2-9~~. *minor*